

# LIS2L02AQ3

# MEMS INERTIAL SENSOR: 2-axis - ±2g/±6g LINEAR ACCELEROMETER

#### Features

- 2.4V TO 5.25V SINGLE SUPPLY OPERATION
- LOW POWER CONSUMPTION
- ±2g/±6g USER SELECTABLE FULL-SCALE
- 0.3mg RESOLUTION OVER 100Hz BANDWIDTH
- EMBEDDED SELF TEST AND POWER DOWN
- OUTPUT VOLTAGE, OFFSET AND SENSITIVITY RATIOMETRIC TO THE SUPPLY VOLTAGE
- HIGH SHOCK SURVIVABILITY
- ECO-PACK COMPLIANT

### Description

The LIS2L02AQ3 is a low-power 2-acis linear capacitive accelerometer that includes a sensing element and an IC interface able to take the information from the sensing element and to provide an analog signal to the external world.

The sensing element, capable of detecting the acceleration, to manufactured using a dedicated process developed by ST to produce inertial sensors and actuators in silicon.

The IC interface is manufactured using a standard CMOS process that allows high level of integration



to design a dedicated circuit which is trimmed to better match the sensing element character stics.

The LIS2L02AQ3 has a user selectable full scale of  $\pm 2g$ ,  $\pm 6g$  and it is capable of measuring accelerations over a bandwidth of 1.5 KHz for all axes. The device handwidth may be reduced by using external capacitances. A self-test capability allows to chock the mechanical and electrical signal path of the sensor.

The L'S2L02AQ3 is available in plastic SMD vackage and it is specified over an extended temperature range of -40°C to +85°C.

The LIS2L02AQ3 belongs to a family of products suitable for a variety of applications:

- Mobile terminals
- Gaming and Virtual Reality input devices
- Free-fall detection for data protection
- Antitheft systems and Inertial Navigation
- Appliance and Robotics.

| Part number  | Temp range, °C | Package | Packing     |
|--------------|----------------|---------|-------------|
| LIS2L02AQ3   | -40°C to +85°C | QFN-44  | Tray        |
| LIS2L02AQ3TR | -40°C to +85°C | QFN-44  | Tape & Reel |

### Order codes

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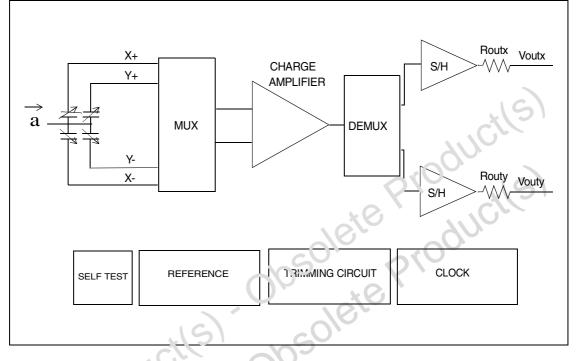
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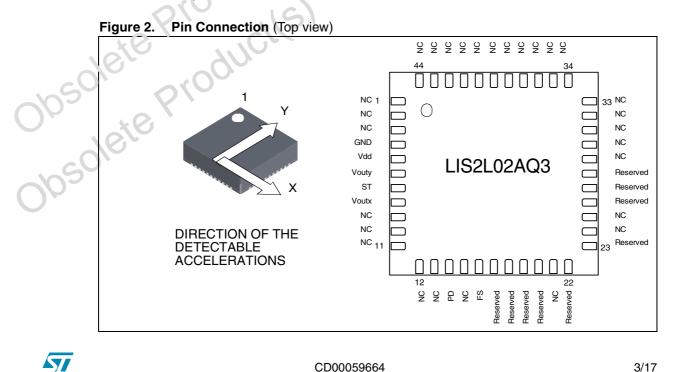
#### **Block Diagram & Pin Description** 1

#### **Block diagram** 1.1

#### Figure 1. **Block Diagram**



#### Pin Description 1.2



| Pin #  | Pin Name | Function                                                                |
|--------|----------|-------------------------------------------------------------------------|
| 1 to 3 | NC       | Internally not connected                                                |
| 4      | GND      | OV supply                                                               |
| 5      | Vdd      | Power supply                                                            |
| 6      | Vouty    | Output Voltage, y-channel                                               |
| 7      | ST       | Self Test (Logic 0: normal mode; Logic 1: Self-test)                    |
| 8      | Voutx    | Output Voltage, x-channel                                               |
| 9-13   | NC       | Internally not connected                                                |
| 14     | PD       | Power Down (Logic 0: normal mode; Logic 1: Power-Down mode;             |
| 15     | NC       | Internally not connected                                                |
| 16     | FS       | Full Scale selection (Logic 0: ±2g Full-scale; Logic 1: +6, Full-scale) |
| 17-18  | Reserved | Leave unconnected                                                       |
| 19     | Reserved | Leave unconnected                                                       |
| 20     | Reserved | Leave unconnected                                                       |
| 21     | NC       | Internally not connected                                                |
| 22-23  | Reserved | Leave unconnected                                                       |
| 24-25  | NC       | Internally not connected                                                |
| 26     | Reserved | Connect to Vdu or GND                                                   |
| 27     | Reserved | Leave unconnected or connect to Vdd                                     |
| 28     | Reserved | Leave unconnected or connect to GND                                     |
| 29-44  | 1.10     | Internally not connected                                                |
| lete P | roduc    |                                                                         |

Table 1. Pin description



# 2 Mechanical and Electrical Specifications

### 2.1 Mechanical Characteristics

#### Table 2. Mechanical Characteristics<sup>1</sup>

(Temperature range -40°C to +85°C) All the parameters are specified @ Vdd =3.3V,  $T = 25^{\circ}C$  unless otherwise noted.

| Symbol   | Parameter                                            | Test Condition                                    | Min.       | Typ. <sup>2</sup> | Max.       | Unit                      |
|----------|------------------------------------------------------|---------------------------------------------------|------------|-------------------|------------|---------------------------|
| <b>A</b> |                                                      | FS pin connected to GND                           | ±1.8       | ±2.0              |            | g                         |
| Ar       | Acceleration Range <sup>3</sup>                      | FS pin connected to<br>Vdd                        | ±5.4       | ±6.0              | ctl        | g                         |
| So       | Sensitivity <sup>4</sup>                             | Full-scale = 2g                                   | Vdd/5-10%  | Vdd/5             | vc'a/5+10% | V/g                       |
| 30       | Sensitivity                                          | Full-scale = 6g                                   | Vdd/15-10% | Vc:2/15           | Vdd/15+10% | V/g                       |
| SoDr     | Sensitivity Change Vs<br>Temperature                 | Delta from +25°C                                  | X          | ±0.01             | , , Ctl    | %/°C                      |
| Voff     | Zero-g Level <sup>4</sup>                            | T = 25°C                                          | Vdd/2 6 %  | Vdd/2             | Vdd/2+6%   | V                         |
| OffDr    | Zero-g Level Change Vs<br>Temperature                | Delta from +25°C                                  | DS.        | ±0.2              |            | mg/°C                     |
| NL       | Non Linearity <sup>5</sup>                           | Best fit straight line<br>Full-scale = 2g         | 101        | ±0.3              | ±1.5       | % FS                      |
| CrossAx  | Cross-Axis <sup>6</sup>                              | de la                                             | S          | ±2                | ±4         | %                         |
| An       | Acceleration Noise<br>Density                        | /ud=3.3V;<br>Full-scale = 2g                      |            | 30                |            | $\frac{\mu g}{\sqrt{Hz}}$ |
|          | Sc:/ Test Output Voltage                             | T = 25°C<br>Vdd=3.3V<br>Full-scale = 2g<br>X axis | 20         | 50                | 100        | mV                        |
| Vt       | Change <sup>7,8,9</sup>                              | T = 25°C<br>Vdd=3.3V<br>Full-scale = 2g<br>Y axis | -20        | -50               | -100       | mV                        |
| Fres     | Sensing Element<br>Resonance Frequency <sup>10</sup> | all axes                                          | 1.5        |                   |            | KHz                       |
| Тор      | Operating Temperature<br>Range                       |                                                   | -40        |                   | +85        | °C                        |
| Wh       | Product Weight                                       |                                                   |            | 0.2               |            | gram                      |

Note: 1 The product is factory calibrated at 3.3V. The device can be powered from 2.4V to 5.25V. Voff, So and Vt parameters will vary with supply voltage.

2 Typical specifications are not guaranteed



- 3 Guaranteed by wafer level test and measurement of initial offset and sensitivity
- 4 Zero-g level and sensitivity are essentially ratiometric to supply voltage
- 5 Guaranteed by design
- 6 Contribution to the measuring output of the inclination/acceleration along any perpendicular axis
- 7 Self test "output voltage change" is defined as Vout<sub>(Vst=Logic1)</sub>-Vout<sub>(Vst=Logic0)</sub>
- 8 Self test "output voltage change" varies cubically with supply voltage
- 9 When full-scale is set to ±6g, self-test "output voltage change" is one third of the specified value
- 10 Minimum resonance frequency Fres=1.5KHz. Sensor bandwidth= $1/(2^*\pi^*110K\Omega^*Cload)$  with Cload>1nF.

#### 2.2 Electrical Characteristics

#### Table 3. Electrical Characteristics<sup>1</sup>

(Temperature range -40°C to +85°C) All the parameters are specified @ Vdd =3.3V, T=25°C unless otherwise noted

| Symbol | Parameter                                    | Test Condition                           | Min | Typ. <sup>2</sup> | Max. | Unit |
|--------|----------------------------------------------|------------------------------------------|-----|-------------------|------|------|
| Vdd    | Supply Voltage                               |                                          | 2.4 | 3.3               | 5.25 | V    |
| ldd    | Supply Current                               | mean value<br>PD pin connected to<br>GND |     | 0.85              | 1.5  | mA   |
| IddPdn | Supply Current in Power<br>Down Mode         | rms value<br>ריש connected to Vdd        | 26. | 2                 | 5    | μA   |
| Vst    |                                              | Logic 0 level                            | 0   |                   | 0.8  | V    |
| VSI    | Self Test Input                              | Logic 1 level                            | 2.2 |                   | Vdd  | V    |
| Rout   | Output: ווּוֹי) אָסעווכפ                     | 16                                       | 80  | 110               | 140  | kΩ   |
| Cload  | Caracitive Load Drive <sup>3</sup>           |                                          | 320 |                   |      | pF   |
| Ton    | Turn-On Time at Exit<br>From Power Down Mode | Cload in μF                              |     | 550*Cload+0.3     |      | ms   |
| Гор    | Operating Temperature<br>Range               |                                          | -40 |                   | +85  | °C   |

Note: 1 The product is factory calibrated at 3.3V

2 Typical specifications are not guaranteed

3 Minimum resonance frequency Fres=1.5KHz. Sensor bandwidth=1/(2\*π\*110KΩ\*Cload) with Cload>1nF



#### 2.3 Absolute maximum ratings

Stresses above those listed as "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

| Symbol           | Ratings                                       | Maximum Value      | Unit                                         |
|------------------|-----------------------------------------------|--------------------|----------------------------------------------|
| Vdd              | Supply voltage                                | -0.3 to 7          | V                                            |
| Vin              | Input Voltage on Any Control pin (FS, PD, ST) | -0.3 to Vdd +0.3   | V                                            |
| A <sub>POW</sub> | Acceleration (Any axis, Powered, Vdd=3.3V)    | 3000g for 0.5 ms   | 6                                            |
| -POW             | Acceleration (Any axis, Fowered, Vdu=3.5V)    | 10000g for 0.1 ms  | <u>,                                    </u> |
| A                | Acceleration (Apy axis Nat powered)           | 3000g for 0.5 m3   |                                              |
| A <sub>UNP</sub> | Acceleration (Any axis, Not powered)          | 10000 j tor 0.1 ms |                                              |
| T <sub>STG</sub> | Storage Temperature Range                     | -40 to +125        | °C                                           |
|                  | i al                                          | 2KV HBM            |                                              |
| ESD              | Electrostatic Discharge Protection            | 200V MM            |                                              |
|                  | 1050                                          | 1500V CDM          |                                              |

 Table 4.
 Absolute maximum ratings



This is a Mechanical Shock pensitive device, improper handling can cause permanent damages to the part



This is an ESD sensitive device, improper handling can cause permanent damages to the part

# 2.4 Terminology

**Sensitivity** describes the gain of the sensor and can be determined by applying 1g occeleration to it. As the sensor can measure DC accelerations this can be done easily by pointing the axis of interest towards the center of the earth, note the output value, rotate the sensor by 180 degrees (point to the sky) and note the output value again thus applying  $\pm 1g$  acceleration to the sensor. Subtracting the larger output value from the smaller one and dividing the result by 2 will give the actual sensitivity of the sensor. This value changes very little over temperature (see sensitivity change vs. temperature) and also very little over time. The Sensitivity Tolerance describes the range of Sensitivities of a large population of sensors.

**Zero-g level** describes the actual output signal if there is no acceleration present. A sensor in a steady state on a horizontal surface will measure 0g in X axis and 0g in Y axis. The output is ideally for a 3.3V powered sensor Vdd/2 = 1650mV. A deviation from ideal 0-g level (1650mV in this case) is called Zero-g offset. Offset of precise MEMS sensors is to some extend a result of stress to the sensor and therefore the offset can slightly change after mounting the sensor onto a printed circuit board or exposing it to extensive mechanical stress. Offset changes little over temperature - see "Zero-g level change vs. temperature" - the Zero-g level of an individual sensor is very stable over lifetime. The Zero-g level tolerance describes the range of zero-g levels of a population of sensors.



**Self Test** allows to test the mechanical and electrical part of the sensor. By applying a digital signal to the ST input pin an internal reference is switched to a certain area of the sensor and creates a defined deflection of the moveable structure. The sensor will generate a defined signal and the interface chip will perform the signal conditioning. If the output signal changes with the specified amplitude than the sensor is working properly and the parameters of the interface chip are within the defined specifications.

Output impedance describes the resistor inside the output stage of each channel. This resistor is part of a filter consisting of an external capacitor of at least 320pF and the internal resistor. Due to the high resistor level only small, inexpensive external capacitors are needed to generate low corner frequencies. When interfacing with an ADC it is important to use high input , is recommined and it is a recommined and it is recommined and it is a recommined and reco impedance input circuitries to avoid measurement errors. Note that the minimum load capacitance forms a corner frequency beyond the resonance frequency of the sensor. For a flat frequency response a corner frequency well below the resonance frequency is recommended. In general the smallest possible bandwidth for an particular application should be chosen to get

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# 3 Functionality

The LIS2L02AQ3 is a high performance, low-power, analog output 2-axis linear accelerometer packaged in a QFN package. The complete device includes a sensing element and an IC interface able to take the information from the sensing element and to provide an analog signal to the external world.

### 3.1 Sensing element

A proprietary process is used to create a surface micro-machined accelerometer. The technology allows to carry out suspended silicon structures which are attached to the substrate in a few points called anchors and are free to move in the direction of the sensed acceleration. To be compatible with the traditional packaging techniques a cap is placed on top of the sensing element to avoid blocking the moving parts during the moulding place of the plastic encapsulation.

When an acceleration is applied to the sensor the proof mass displaces from its nominal position, causing an imbalance in the capacitive half-bridge. This imbalance is measured using charge integration in response to a voltage pulse applied to the sense capacitor.

At steady state the nominal value of the capacitors are 10% pF and when an acceleration is applied the maximum variation of the capacitive load is up to 100fF.

### 3.2 IC Interface

In order to increase robustness and immunity against external disturbances the complete signal processing chain uses a fully differential structure. The final stage converts the differential signal into a single-orden one to be compatible with the external world.

The signals of the scheining element are multiplexed and fed into a low-noise capacitive charge amplifier that implements a Correlated Double Sampling system (CDS) at its output to cancel the offset and the 1/f noise. The output signal is de-multiplexed and transferred to three different S&Hs, one for each channel and made available to the outside.

Les low noise input amplifier operates at 200 kHz while the three S&Hs operate at a sampling frequency of 66 kHz. This allows a large oversampling ratio, which leads to in-band noise reduction and to an accurate output waveform.

All the analog parameters (zero-g level, sensitivity and self-test) are ratiometric to the supply voltage. Increasing or decreasing the supply voltage, the sensitivity and the offset will increase or decrease almost linearly. The self test voltage change varies cubically with the supply voltage.

## 3.3 Factory calibration

The IC interface is factory calibrated for sensitivity (So) and Zero-g level (Voff). The trimming values are stored inside the device by a non volatile structure. Any time the device is turned on, the trimming parameters are downloaded into the registers to be employed during the normal operation. This allows the user to employ the device without further calibration.



## 4 Application hints

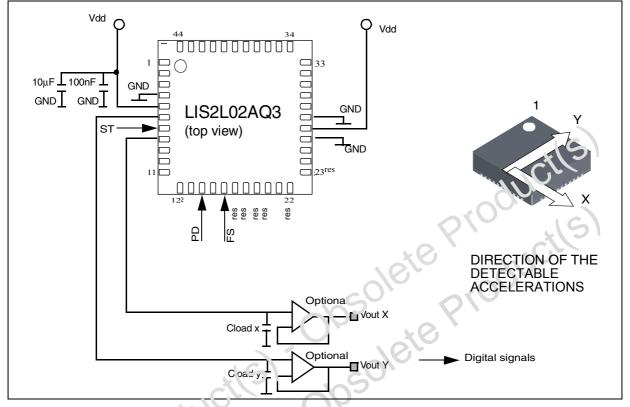


Figure 3. LIS2L02AQ3 Electrical Connection

Power supply decoupling capacitors (100nF ceramic or polyester + 10µF Aluminum) should be placed as near as cossible to the device (common design practice).

The LIS2 02AQ3 allows to band limit Voutx, Vouty and Voutz through the use of external capacitors. The re-commended frequency range spans from DC up to 1.5 KHz. In particular, capacitors must be added at output pins to implement low-pass filtering for antialiasing and noise reduction. The equation for the cut-off frequency ( $f_t$ ) of the external filters is:

$$f_t = \frac{1}{2\pi \cdot R_{out} \cdot C_{load}(x, y, z)}$$

Taking into account that the internal filtering resistor (R<sub>out</sub>) has a nominal value equal to 110kOhm, the equation for the external filter cut-off frequency may be simplified as follows:

$$f_{t} = \frac{1.45\mu F}{C_{load}(x, y, z)}$$

The tolerance of the internal resistor can vary typically of  $\pm 20\%$  within its nominal value of  $110k\Omega$ ; thus the cut-off frequency will vary accordingly. A minimum capacitance of 320 pF for  $C_f(x, y, z)$  is required in any case.



| commercial available. |                 |  |  |
|-----------------------|-----------------|--|--|
| Cut-off frequency     | Capacitor value |  |  |
| 1 Hz                  | 1500 nF         |  |  |
| 10 Hz                 | 150 nF          |  |  |
| 20 Hz                 | 68 nF           |  |  |
| 50 Hz                 | 30 nF           |  |  |
| 100 Hz                | 15 nF           |  |  |
| 200 Hz                | 6.8 nF          |  |  |
| 500 Hz                | 3 nF            |  |  |

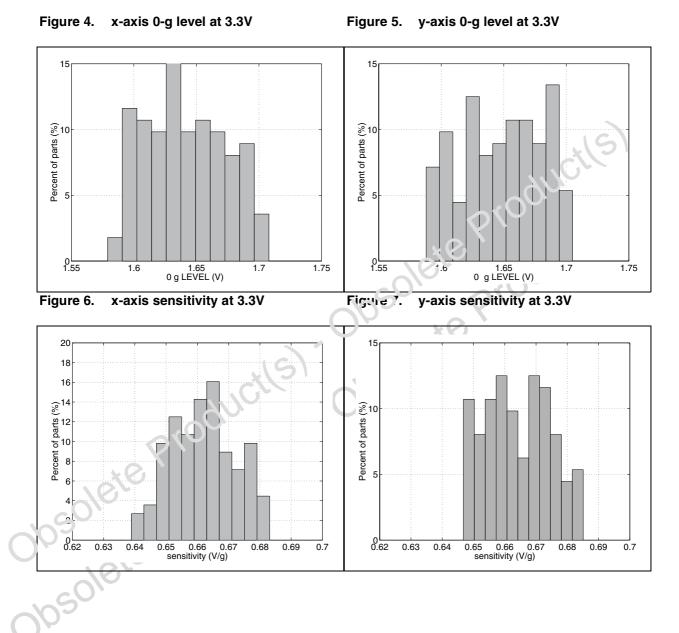
#### Table 5. Filter Capacitor Selection, C<sub>f</sub> (x,y,z). Capacitance value approximated closest a a monarai al availabla

adied for so testing he soldering recommendation obsolete product(s) - Obsolete product( The QFN44 package is lead free and green package qualified for somering heat resistance according to JEDEC J-STD-020C. Land pattern and soldering recommendations are available



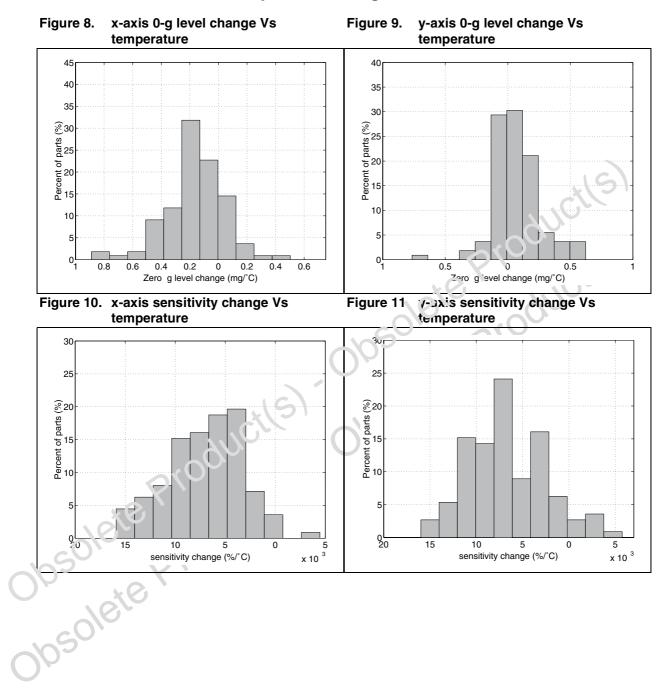
# **5** Typical performance characteristics

### 5.1 Mechanical Characteristics at 25°C





# 5.2 Mechanical Characteristics derived from measurement in the -40°C to +85°C temperature range

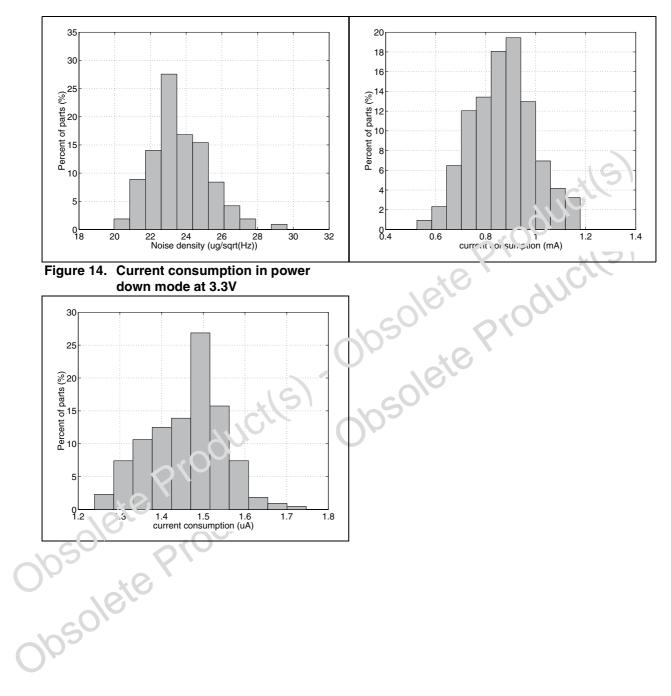




### 5.3 Electrical characteristics at 25°C

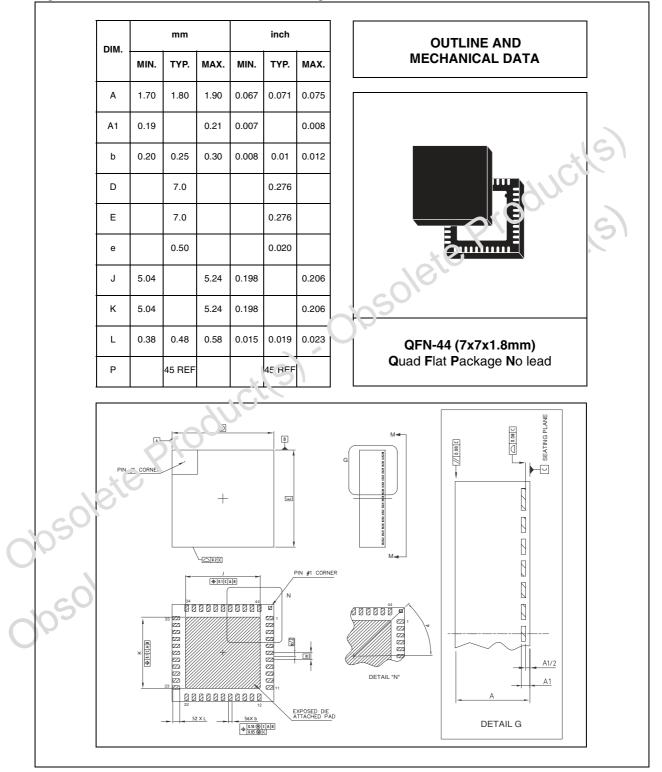
#### Figure 12. Noise density at 3.3V

Figure 13. Current consumption at 3.3V





# 6 Package Information



#### Figure 15. QFN-44 Mechanical Data & Package Dimensions

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# 7 Revision history

| Date         | Revision | Changes      |
|--------------|----------|--------------|
| 15-July-2005 | 1        | First issue. |

Obsolete Product(s) - Obsolete Product(s) Obsolete Product(s) - Obsolete Product(s)



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